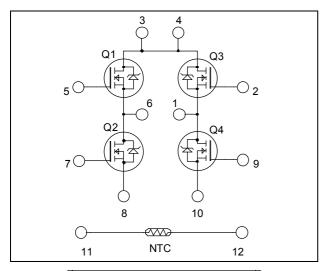
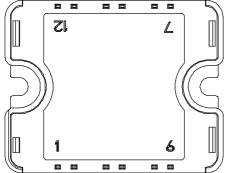


Full - Bridge Super Junction MOSFET Power Module

 $V_{DSS} = 900V$ $R_{DSon} = 120 \text{m}\Omega \text{ max } @ \text{Tj} = 25^{\circ}\text{C}$ $I_D = 30A$ @ $Tc = 25^{\circ}C$





Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Ultra low R_{DSon}
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		900	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	30	
I_D	Continuous Drain Current T _c	$T_c = 80$ °C	23	Α
I_{DM}	Pulsed Drain current		75	
V_{GS}	Gate - Source Voltage		±20	V
R _{DSon}	Drain - Source ON Resistance		120	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		8.8	A
E_{AR}	Repetitive Avalanche Energy		2.9	mJ
E_{AS}	Single Pulse Avalanche Energy		1940	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 900V$ $T_j = 25^{\circ}C$			100	μA
		$V_{GS} = 0V, V_{DS} = 900V$ $T_j = 125^{\circ}C$		500		
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 26A$		100	120	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 3mA$	2.5	3	3.5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V ; V_{DS} = 100V$		6.8		nF
C_{oss}	Output Capacitance	f = 1MHz		0.33		111
Q_{g}	Total gate Charge	$V_{GS} = 10V$		270		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 400V$		32		nC
Q_{gd}	Gate – Drain Charge	$I_D = 26A$		115		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		70		
T_{r}	Rise Time	$V_{GS} = 10V$		20		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{D}} = 26A$		400		ns
T_{f}	Fall Time	$R_G = 7.5\Omega$		25		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1.5		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 600V$ $I_D = 26A ; R_G = 7.5\Omega$		0.75		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2.1		Т
E_{off}	Turn-off Switching Energy	$V_{GS} = 10V ; V_{Bus} = 600V$ $I_D = 26A ; R_G = 7.5\Omega$		0.85		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			30	Α
	(Body diode)		$Tc = 80^{\circ}C$			23	A
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -26A$			0.8	1.2	V
t_{rr}	Reverse Recovery Time	$I_S = -26A$	$T_j = 25$ °C		920		ns
Qrr	Reverse Recovery Charge	$V_R = 400V$ $di_S/dt = 200A/\mu s$	$T_j = 25$ °C		30		μС



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance				0.50	°C/W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight				80	g	

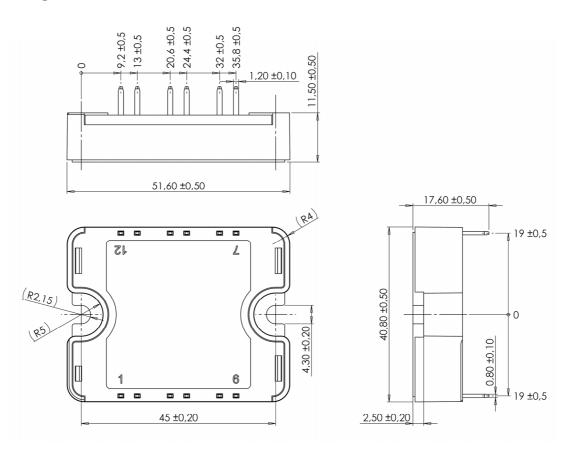
$Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$			5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K
$\Delta B/B$	T_{C}	100°C	4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

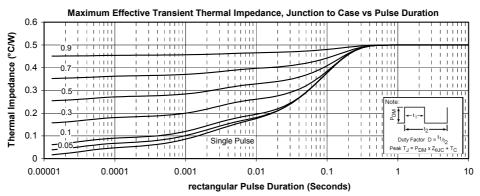
SP1 Package outline (dimensions in mm)

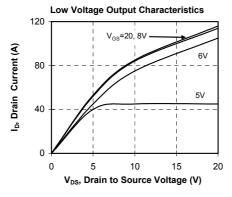


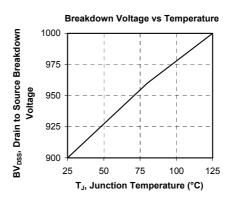
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

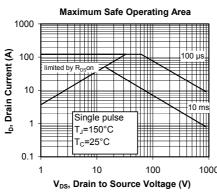


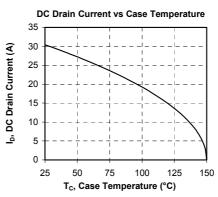
Typical performance Curve

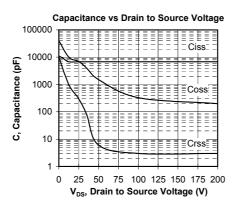


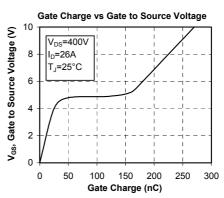




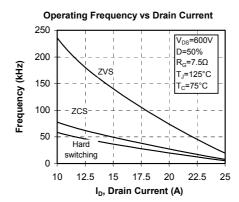


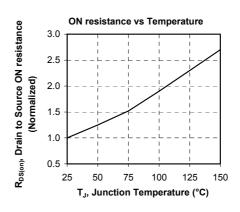


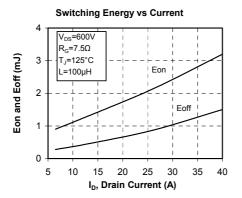


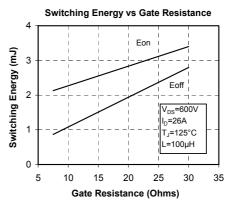












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